

Ka-Band Volume Production Oscillator, 35 GHz, +18 dBm, ±2.0 GHz

Description:

Model SOL-35318-28-G1-1 is a volume-production ready, Ka Band Gunn oscillator that utilizes a high performance GaAs Gunn diode and high Q cavity to achieve excellent phase noise and power stability. The oscillator is designed for fixed frequency applications, however, the frequency can be adjusted by ±2.0 GHz using the self-locking set screw provided.



Features:

- Low Cost and Production Ready
- Mechanical tuning ability
- Low AM/FM Noise and Harmonics
- High Frequency and Power Stability

Applications:

- **Traffic Control Systems**
- **Communication Systems**
- **Radar Systems**

Electrical Specifications:

Parameter	Minimum	Typical	Maximum
Center Frequency		35 GHz	
Power Output	+17 dBm	+18 dBm	
Mechanical Tuning Range	±1,000 MHz	±2,000 MHz	
Harmonic Emissions		-20 dBc	
Phase Noise @ 100 KHz offset		-95 dBc/Hz	
Frequency Stability			-0.3 MHz/°C
Power Output Stability			-0.03 dB/°C
Bias Voltage	A STATE OF THE PARTY OF THE PAR	+5.5 V _{DC}	+6 V _{DC}
Bias Current		650 mA	
Specification Temperature		+25 °C	
Operating Temperature	-40 °C		+85 °C

Note: Actual tuning bandwidth is wider, ±3.0 GHz typical.

Mechanical Specifications:

Mechanical Specificat		
Item	Specification	
RF Port	WR-28 Waveguide with UG-599/U Flange	
Cavity Material	Aluminum	
Finish	Chem Film	
Weight	0.6 Oz	
Outline	OL-A1	

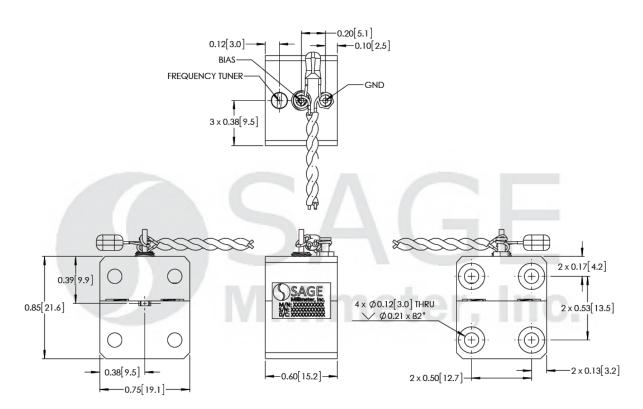


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Mechanical Outline: (Unless otherwise specified, all dimensions are in inches [millimeters])



Note:

- SAGE Millimeter, Inc. reserves the right to change the information presented without notice.
- The center frequency can be set at any frequency point in the range of 33 to 35 GHz.

Caution:

- Reversing polarity bias will destroy the device.
- Exceeding absolute maximum ratings shown will damage the device.
- The device is static sensitive. Always follow ESD rules when working with the device.
- Any foreign objects in the waveguide will cause performance degradation and possible device damage.
- The case temperature of the device shall never exceed <u>+85 °C</u>. Use an additional heatsink or fan if necessary.



